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**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant : HWANG et al. Confirmation No: 2598  
Appl. No. : 10/022,349  
Filed : December 20, 2001  
Title : A SINGLE-CHIP STRUCTURE OF SILICON GERMANIUM  
PHOTODETECTOR AND HIGH-SPEED TRANSISTOR

TC/A.U. : 2814  
Examiner : D. Wille

Docket No.: : YAMA3001/REF  
Customer No: : 23364

**RESPONSE TO NOTICE OF NON-COMPLIANT AMENDMENT**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

This is in response to the Official Action of January 15, 2004, in connection with the above-identified application. This response is timely filed.

Please amend the application as follows:

Amendments to the claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks begin on page 7 of this paper.